



BAS116T, BAW156T, BAV170T, BAV199T

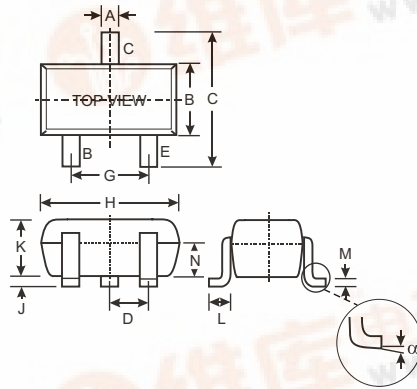
SURFACE MOUNT LOW LEAKAGE DIODE

Features

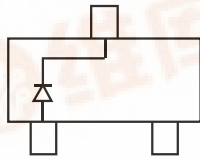
- Ultra-Small Surface Mount Package
- Very Low Leakage Current

Mechanical Data

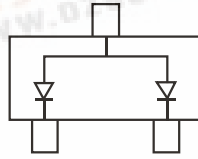
- Case: SOT-523, Molded Plastic
- Case material - UL Flammability Rating Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagrams Below
- Marking: See Diagrams Below & Page 3
- Weight: 0.002 grams (approx.)
- Ordering Information: See Page 3



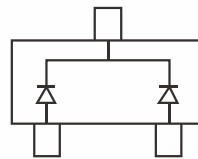
SOT-523			
Dim	Min	Max	Typ
A	0.15	0.30	0.22
B	0.75	0.85	0.80
C	1.45	1.75	1.60
D	—	—	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
J	0.00	0.10	0.05
K	0.60	0.80	0.75
L	0.10	0.30	0.22
M	0.10	0.20	0.12
N	0.45	0.65	0.50
α	0°	8°	—
All Dimensions in mm			



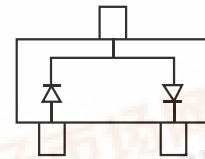
BAS116T Marking: 50



BAW156T Marking: 53



BAV170T Marking: 51



BAV199T Marking: 52

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

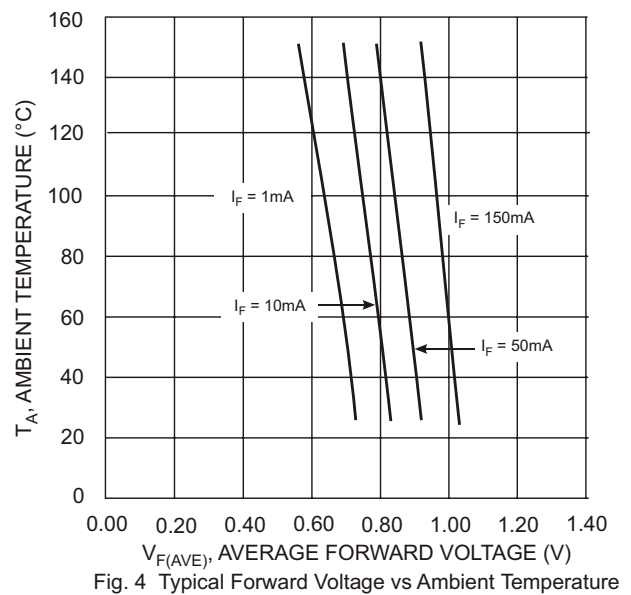
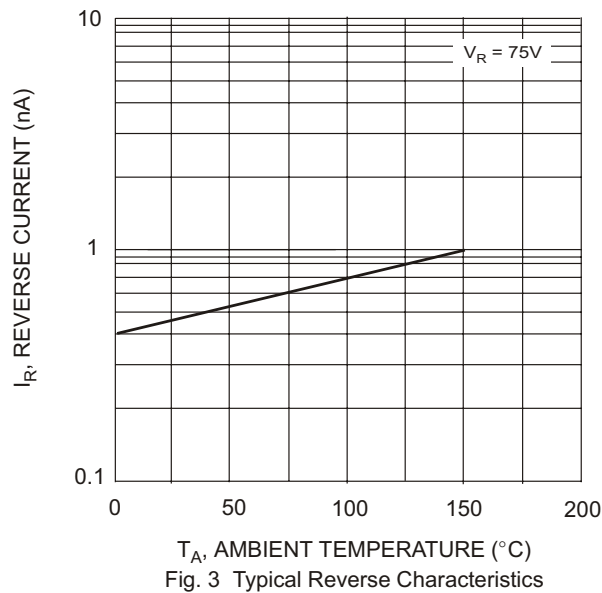
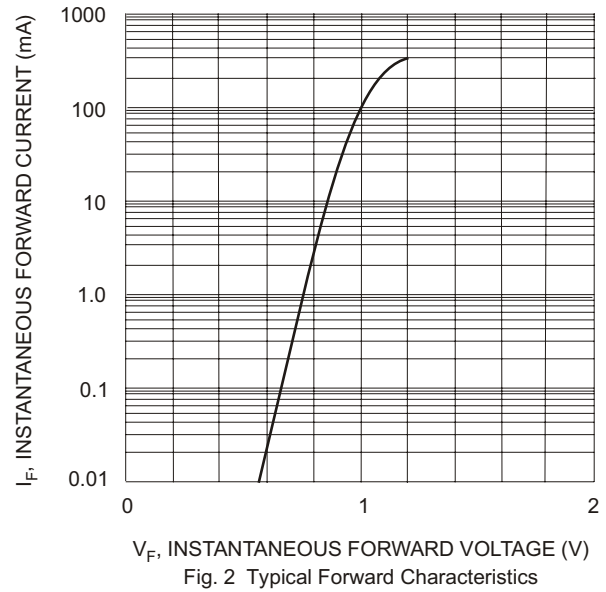
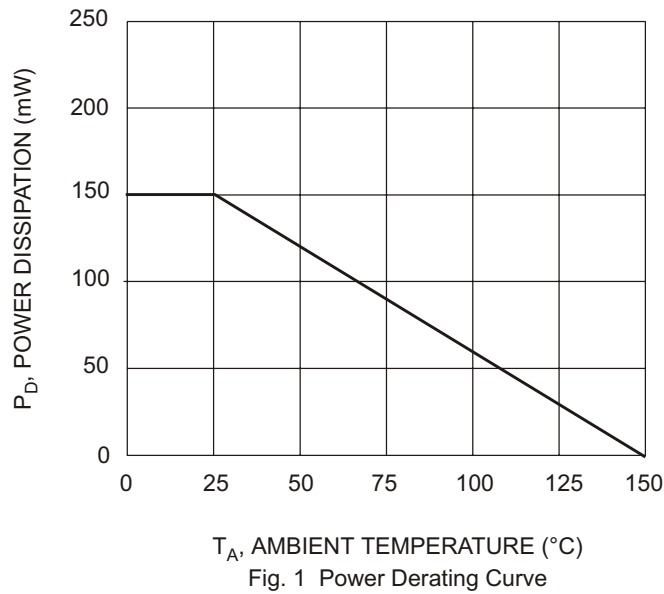
Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	85	V
RMS Reverse Voltage	$V_{R(RMS)}$	60	V
Forward Continuous Current (Note 1)	I_{FM}	215	mA
		125	
Repetitive Peak Forward Current	I_{FRM}	500	mA
Non-Repetitive Peak Forward Surge Current	I_{FSM}	4.0	A
@ $t = 1.0\mu\text{s}$		1.0	
@ $t = 1.0\text{ms}$		0.5	
Power Dissipation (Note 1)	P_d	150	mW
Thermal Resistance Junction to Ambient Air (Note 1)	$R_{\theta JA}$	833	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150	$^\circ\text{C}$

Notes: 1. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	$V_{(BR)R}$	85	—	—	V	$I_R = 100\mu\text{A}$
Forward Voltage (Note 2)	V_F	—	—	0.90 1.0 1.1 1.25	V	$I_F = 1.0\text{mA}$ $I_F = 10\text{mA}$ $I_F = 50\text{mA}$ $I_F = 150\text{mA}$
Leakage Current (Note 2)	I_R	—	—	5.0 80	nA nA	$V_R = 75\text{V}$ $V_R = 75\text{V}, T_j = 150^\circ\text{C}$
Total Capacitance	C_T	—	2	—	pF	$V_R = 0, f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}	—	—	3.0	μs	$I_F = I_R = 10\text{mA}$, $t_{rr} = 0.1 \times I_R, R_L = 100\Omega$

Notes: 2. Short duration test pulse used to minimize self-heating effect.

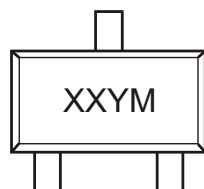


Ordering Information (Note 3)

Device	Packaging	Shipping
BAS116T-7	SOT-523	3000/Tape & Reel
BAW156T-7	SOT-523	3000/Tape & Reel
BAV170T-7	SOT-523	3000/Tape & Reel
BAV199T-7	SOT-523	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



XX = Product Type Marking Code (See Page 1, e.g. 50 = BAS116T)
 YM = Date Code Marking
 Y = Year (ex: N = 2002)
 M = Month (ex: 9 = September)

Date Code Key

Year	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	M	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D